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## **DATA SHEET**



# NPN SILICON RF TRANSISTOR

NE68539 / 2SC4957 JEITA Part No.

## NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN MINIMOLD

#### **FEATURES**

- · Low Noise, High Gain
- · Low Voltage Operation
- Low Reverse Transfer Capacitance
   Cre = 0.3 pF TYP.
- · 4-pin minimold Package

#### **★ ORDERING INFORMATION**

Part Number	Quantity	Supplying Form
NE68539E-A 2SC4957 -A	50 pcs (Non reel)	8 mm wide embossed taping     Pin 3 (Base), Pin 4 (Emitter) face to perforation side of the tape
NE68539E-T1-A 2SC4957-T1-A	3 kpcs/reel	

**Remark** To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25^{\circ}C$ )

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	9	V
Collector to Emitter Voltage	VCEO	6	٧
Emitter to Base Voltage	VEBO	2	V
Collector Current	lc	30	mA
Total Power Dissipation	Ptot Note	180	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	−65 to +150	°C

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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## **ELECTRICAL CHARACTERISTICS (TA = +25°C)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	-	-	100	nA	
Emitter Cut-off Current	ІЕВО	V <sub>EB</sub> = 1 V, I <sub>C</sub> = 0 mA	-	-	100	nA	
DC Current Gain	hfE Note 1	VcE = 3 V, Ic = 10 mA	75	-	150	-	
RF Characteristics							
Gain Bandwidth Product	f⊤	VcE = 3 V, Ic = 10 mA	-	12	-	GHz	
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	VcE = 3 V, Ic = 10 mA, f = 2.0 GHz	9	11		dB	
Noise Figure	NF	VcE = 3 V, Ic = 3 mA, f = 2.0 GHz	-	1.5	2.5	dB	
Reverse Transfer Capacitance	Cre Note 2	VcB = 3 V, IE = 0 mA, f = 1.0 MHz	-	0.3	0.5	pF	

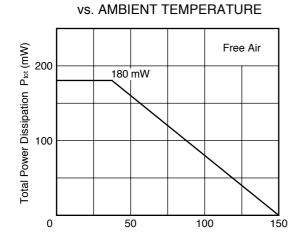
**Notes 1.** Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

2. Collector to base capacitance when the emitter grounded

**hfe CLASSIFICATION** 

Rank	T83		
Marking	T83		
hre Value	75 to 150		

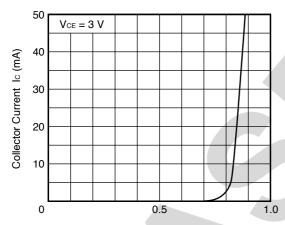
#### TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



**TOTAL POWER DISSIPATION** 

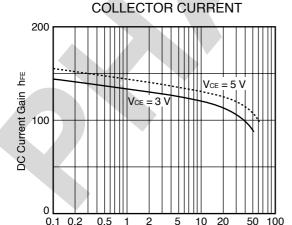
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

Ambient Temperature TA (°C)



Base to Emitter Voltage VBE (V)

DC CURRENT GAIN vs.



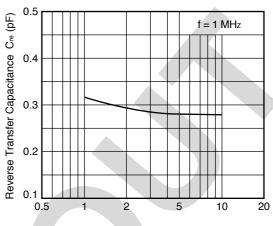
0.5

Remark The graphs indicate nominal characteristics.

Collector Current Ic (mA)

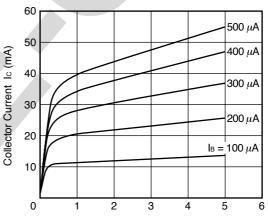
5

#### REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



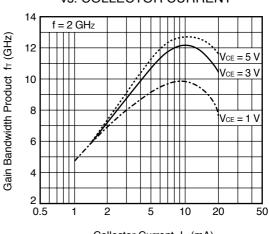
Collector to Base Voltage VcB (V)

#### COLLECTOR CURRENT vs. **COLLECTOR TO EMITTER VOLTAGE**

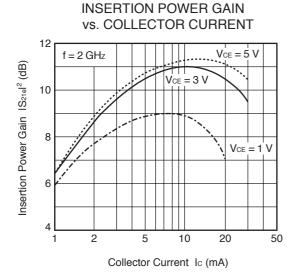


Collector to Emitter Voltage VcE (V)

#### **GAIN BANDWIDTH PRODUCT** vs. COLLECTOR CURRENT



Collector Current Ic (mA)



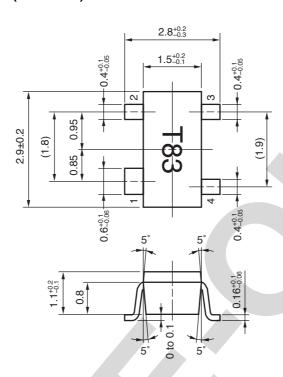
**Remark** The graphs indicate nominal characteristics.

#### **★ S-PARAMETERS**

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

#### **★ PACKAGE DIMENSIONS**

## 4-PIN MINIMOLD PACKAGE (UNIT: mm)



## **PIN CONNECTIONS**

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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